

HITANO ENTERPRISE CORP.

1N5400 THRU 1N5408

TECHNICAL SPECIFICATIONS OF SILICON RECTIFIER

VOLTAGE RANGE – 50 to 1000 Volts

CURRENT – 3.0 Amperes

FEATURES

- Low cost
- Low leakage
- Low forward voltage drop
- * High current capability

MECHANICAL DATA

*Case: Molded plastic

*Epoxy: UL 94V -0 rate flame retardant

*Lead: MIL-STD-202E, Method 208 guaranteed.

*Polarity: Color band denotes cathode end

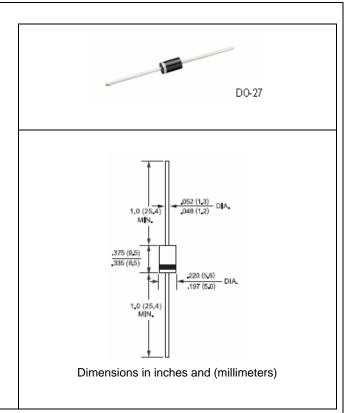
*Mounting position: Any *Weight: 1.18 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%



		SYMBOL	1N5400	1N5401	1N5402	1N5404	1N5406	1N5407	1N5408	UNITS
Maximum Recurrent Peak Reverse Voltage		V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage		V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current .375*(9.5mm) lead length at TL =105°C		lo	3.0							Amps
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		I _{FSM}	200							Amps
Maximum Instantaneous Forward Voltage at 3.0ADC		V _F	1.1							Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage	@ T _{A=25℃}		5.0							μ Amps
	@ T _{A=100℃}	I _R	500							
Maximum Full Load Reverse Current Average, Full Cycle .375*(9.5mm) lead length at TL=75℃			30							μ Sec
Typical Junction Capacitance (Note)		CJ	40							pF
Typical Thermal Resistance		ReJA	30							°CW

NOTES: 1. Measured at 1 MHZ and applied reverse voltage of 4.0 volts

RATING AND CHARACTERISTIC CURVES (1N5400 THRU 1N5408)

